

# Large area high efficiency broad bandwidth 800 nm dielectric gratings for high energy laser pulse compression

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**Abstract:** We have demonstrated broad bandwidth large area (229 mm x 114 mm) multilayer dielectric diffraction gratings for the efficient compression of high energy 800 nm laser pulses at high average power. The gratings are etched in the top layers of an aperiodic  $(\text{Nb}_{0.5}\text{Ta}_{0.5})_2\text{O}_5\text{-SiO}_2$  multilayer coating deposited by ion beam sputtering. The mean efficiency of the grating across the area is better than 97% at the center wavelength and remains above 96% at wavelengths between 820 nm and 780 nm. The gratings were used to compress 5.5 J pulses from a Ti:sapphire laser with an efficiency above 80 percent.

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## 1. Introduction

The grating compressor [1] is one of the most critical components of a high power chirped pulse amplification (CPA) laser system [2]. Requirements for the diffraction gratings include: high diffraction efficiency, high damage threshold, and often the ability to withstand high average powers. Until recently, CPA laser systems have almost exclusively made use of metallic diffraction gratings, in which the diffractive structure is typically coated with a thin gold film. These gold-coated pulse compression gratings have allowed the implementation of a number of high power laser systems around the world [3–5]. An all-dielectric grating alternative was first proposed in 1991 as a possible solution to improve throughput, increase the damage threshold and maximize average power operation [6]. Moreover, dielectric gratings are less prone to experience the degradation that is frequently observed in gold coated gratings. Since then, the fabrication method pioneered at Lawrence Livermore National Laboratory has allowed the production of very large area multilayer dielectric (MLD) gratings operating at a centered wavelength  $\lambda = 1 \mu\text{m}$  with all the advantages listed above [7,8]. However, it has been difficult to produce a dielectric grating design for pulse compression at  $\lambda = 800 \text{ nm}$ . Recently, results from  $\lambda = 800 \text{ nm}$  all-dielectric  $\text{HfO}_2\text{-SiO}_2$  gratings and metal-dielectric gratings manufactured in 25 mm diameter substrates have been reported [9]. The dielectric gratings were reported to have a diffraction efficiency of 96 percent over a bandwidth of 38 nm, and a high damage threshold.

Hereafter we present results of the development and fabrication of broad bandwidth large area MLD gratings for the compression of Ti:sapphire laser pulses based on a  $(\text{Nb}_{0.5}\text{Ta}_{0.5})_2\text{O}_5\text{-SiO}_2$  multilayer coating. The measured  $-1\text{st}$  order diffraction efficiency of these MLD gratings is better than 97% at 800 nm and above 96% over a spectral bandwidth of at least 40 nm. The gratings were used to compress 5.5 J pulses from a Ti:sapphire laser with an efficiency more than 80 percent.

## 2. Grating design

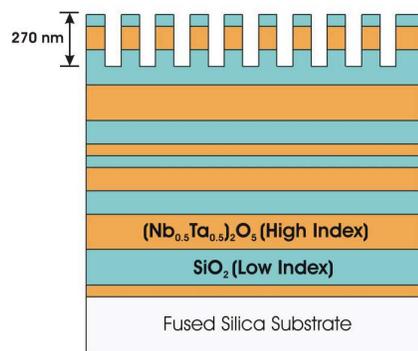


Fig. 1. Schematic diagram of a dielectric multilayer deposited on top of a fused silica substrate. The reflective multilayer stack has 20 layers.

The grating was designed to have a line density of 1740 lines/mm, giving a Littrow angle of 44.1 degrees at a wavelength of 800 nm, while allowing for a large acceptance angle of at least 10 degrees from Littrow. This corresponds to input and output operating angles of  $\sim 35$  and  $\sim 55$  degrees respectively. The grating was designed to have maximum diffraction

efficiency at a center wavelength of 800 nm and a bandwidth acceptance of more than 60 nm. The grating design consists of a MLD high reflectance interference coating with grooves etched into the top layers (Fig. 1). The high reflector (HR) is created by an asymmetric dielectric stack with 20 alternating layers of high  $(\text{Nb}_{0.5}\text{Ta}_{0.5})_2\text{O}_5$  and low  $\text{SiO}_2$  index materials. This material combination was selected because it offers large index contrast and the possibility of designing a large bandwidth grating at 800 nm. The grooves are etched to be 270 nm deep, and reside in the top three layers rather than confined to the low index capping layer, which is a common practice.

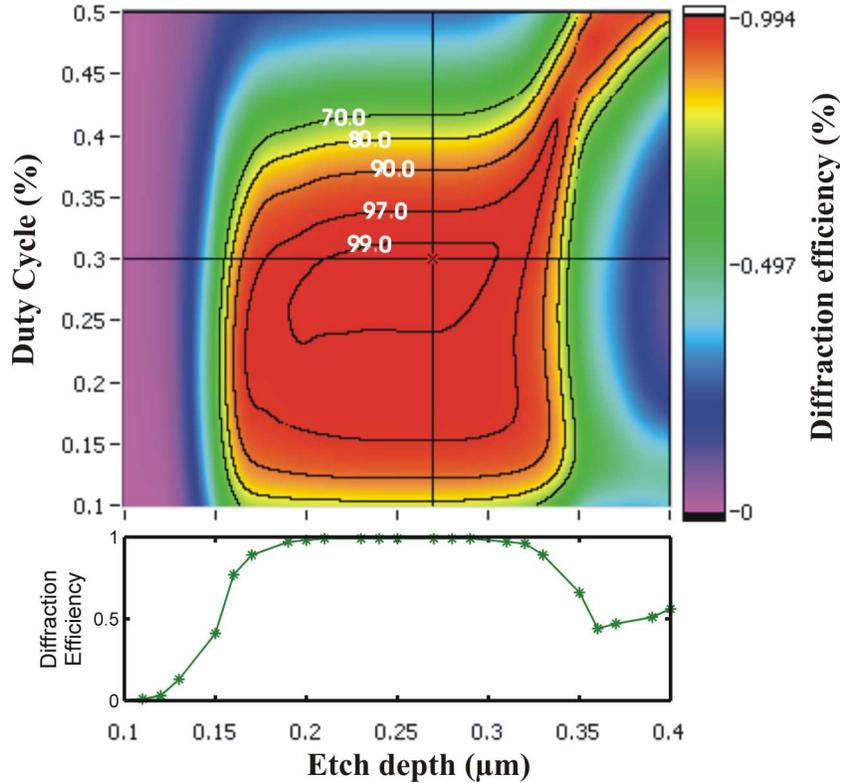


Fig. 2. Simulated diffraction efficiency map of the  $-1$ st order of an 800 nm grating operating at an angle of 38 degrees as a function of etch depth and duty cycle of the line pattern. The contours indicate constant diffraction efficiency. The cut shows the variation of diffraction efficiency versus etch depth at the optimum, 30% duty cycle.

Figure 2 shows the simulated  $-1$ st order diffraction efficiency of the MLD grating operating at an angle of incidence of 38 degrees computed as a function of the groove depth and the linewidth/separation ratio (duty cycle) of the line pattern. Both parameters affect the diffraction efficiency significantly. The crossed lines in Fig. 2 identify the combination of parameters selected for fabrication, a groove depth of 270 nm and a duty cycle of 30%, and the corresponding simulated diffraction efficiency. Figure 3 illustrates the sensitivity of the MLD diffraction efficiency to variations of a few percent to the duty cycle and groove depth. These effects make the manufacturing of MLD gratings very challenging if the process is not well controlled.

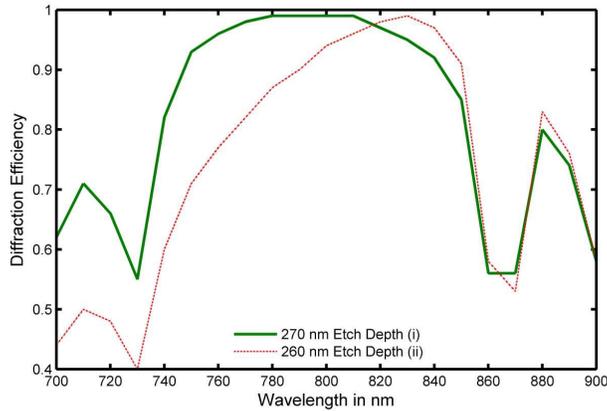


Fig. 3. Simulated diffraction efficiency of the -1st order of an 800 nm grating operating at an angle of 38 degrees. (i) Optimum 270 nm groove depth with a 30% duty cycle (ii) 260 nm groove depth with a 36% duty cycle.

### 3. High reflector design, fabrication and testing

The MLD stack consists of sequential layers of  $\text{SiO}_2$  and  $(\text{Nb}_{0.5}\text{Ta}_{0.5})_2\text{O}_5$  with layer thickness varying from a minimum of 40 nm (thickness of the low index capping layer) to a maximum of 300 nm. The design offers 99.99% reflectivity at a centered wavelength of 800 nm. The reflection at a wavelength of 413 nm, corresponding to the krypton ion laser used in the lithographic process, is less than 10 percent. This requirement ensures minimum degradation of the holographic line pattern due to back-reflections. The MLD stacks were deposited by ion beam sputtering using a Veeco Spector ion beam deposition system equipped with a planetary apparatus capable to accommodate large substrates. The Spector® platform utilized a 16 cm RF deposition source and a 12 cm assist source which provided substrate cleaning and thin film stoichiometry control. Stringent control of layer thicknesses during deposition was required to match the design and maintain a coating reflectivity uniformity of <1% centered at 800 nm across the entire substrate area.

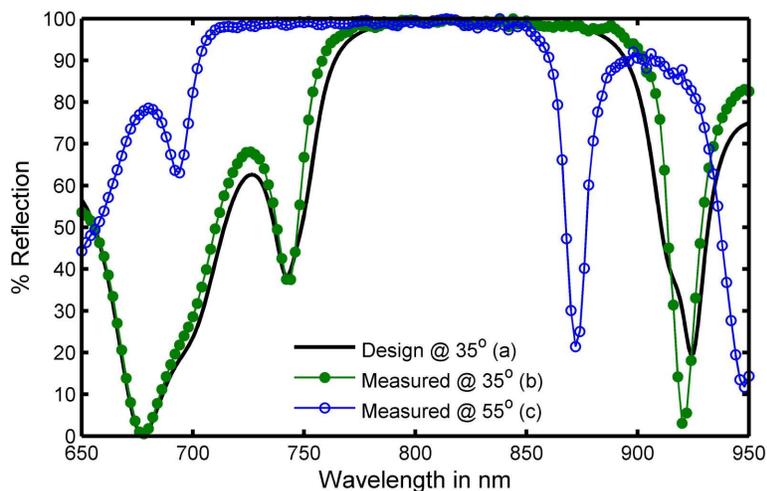


Fig. 4. S-polarization spectral response of the asymmetric 20 layer MLD high reflector. Simulated (a) reflection at 35 degrees, measured reflection at 35 (b) and 55 (c) degrees.

The MLD stack was deposited onto 229 mm x 114 mm fused silica slabs. The measured S-polarization reflection of the MLD coatings obtained by ellipsometry is shown in Fig. 4. The

plot compares the designed reflectivity at 35 degrees incidence angle (a) with the measured response (b). The agreement highlights the reliable layer thickness control obtained with the dual ion beam deposition system. The plot also compares the measured reflectance of the MLD stack at incidence angles of 35 (b) and 55 (c) degrees respectively, showing that the HR interference coating offers a 100 nm spectral window centered around 800 nm.

#### 4. Grating fabrication and performance

The grating structure was printed into the multilayer dielectric coating by interferometric photolithography. A layer of photoresist deposited on top of the multilayer stack was exposed using a holographic exposure tool based on the  $\lambda = 413$  nm line of a krypton ion laser. Following exposure, the substrates were baked to harden the resist after which the fused silica slabs were inserted into a reactive ion-beam etching (RIBE) tool capable of etching submicron features into substrates. Etching was carried out with an etching gas mix of  $\text{CHF}_3$ , Ar and  $\text{O}_2$  using the same protocol described in [8] for the fabrication of 1  $\mu\text{m}$  MLD gratings. As mentioned above, the groove depth has a critical effect on the diffraction efficiency, requiring accurate control of the etching process across the entire grating surface.

The efficiency of the MLD gratings was measured over the entire area of the fused silica slab using the scanning photometry tool described in [10]. Figure 5 shows a map of the  $-1$ st order diffraction efficiency of a completed grating measured at a wavelength of 800 nm and at an incident angle of 38 degrees. A diffraction efficiency of 97.3% with a standard deviation of 0.3% was measured across the full slab area.

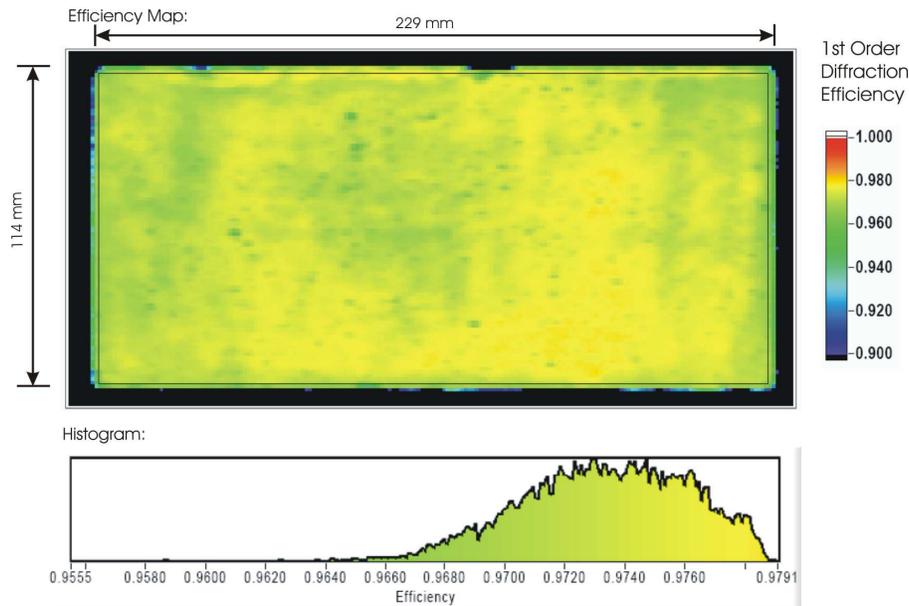


Fig. 5. Map of the  $-1$ st order diffraction efficiency of a 229 mm x 114 mm grating measured at an operating angle of 38 degrees at a wavelength of 800 nm. The mean efficiency is 97.3% with a standard deviation of 0.3%. The histogram shows the distribution of diffraction efficiency over the entire grating area.

The mean diffraction efficiency remained above 96% for wavelengths between 820 nm and 780 nm. Figure 6 compares the measured diffraction efficiency with the design. The design has a large bandwidth acceptance of over 70 nm at 95%  $-1$ st order diffraction efficiency ( $>90$  nm at 90%  $-1$ st order diffraction efficiency). The measured mean diffraction efficiencies show that the grating performs as expected, and furthermore, that the manufacturing process has high reproducibility. This is demonstrated in Table 1 which displays the measured mean diffraction efficiency values of the  $-1$ st order at  $\lambda = 800$  nm for

four different gratings. The values of the diffraction efficiency averaged over a 40 nm bandwidth centered at 800 nm are also shown.

**Table 1. Measured –1st order diffraction efficiencies for four different 229 mm x 114 mm gratings (%)**

	780 nm		800 nm		820 nm		Averaged Diffraction Efficiencies 780-820 nm
	Mean	RMS	Mean	RMS	Mean	RMS	
1	96.8	0.9	97.8	0.2	96.2	0.5	<b>96.9</b>
2	97.2	0.6	96.7	0.3	94.5	0.5	<b>96.1</b>
3	96.8	0.7	97.3	0.3	93.9	0.7	<b>96.0</b>
4	97.8	0.2	96.1	0.7	91.9	1.6	<b>95.3</b>

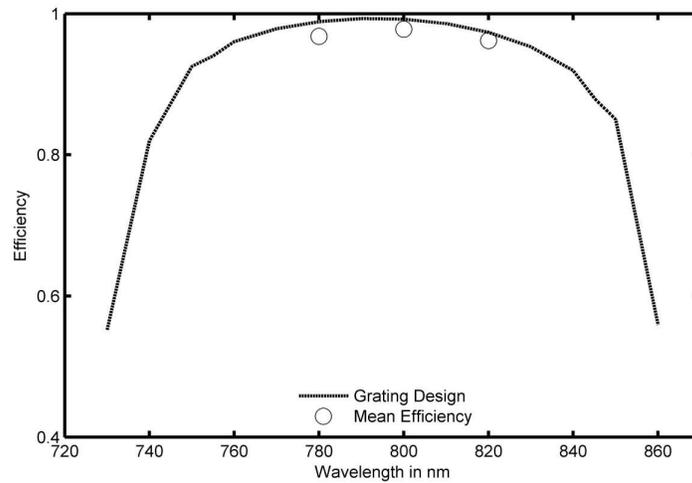


Fig. 6. Diffraction efficiency of the –1st order of an 800 nm grating operating at 38 degrees: The dotted line shows the design simulation of the diffracted light with a 270 nm groove depth. The circles are the measured mean efficiencies of the fabricated 229 mm x 114 mm grating.

## 5. Damage testing of the MLD high reflector and grating

The single-pulse laser damage threshold of the MLD interference coatings and of the completed grating were measured for different laser pulse lengths by adjusting the pulsewidth of a CPA 10 Hz Ti:Sapphire laser. The setup used for the damage threshold measurement is shown schematically in Fig. 7. Two polarizing beam splitters and a waveplate were used to control the laser pulse energy. The samples were irradiated at an operating angle of 55 degrees with an S-polarized beam focused into a ~200  $\mu\text{m}$  diameter spot by a 3 m focal length lens. The beam fluence on the sample was determined by simultaneously monitoring the intensity profile and the laser pulse energy using a high transmission beam splitter. The energy of every shot was monitored with a Gentec TPM-300 power meter and the intensity profile was monitored by imaging the laser beam onto a CCD camera with a 100 mm focal length lens. To determine when damage occurs, the surface of the sample was monitored using a second imaging system composed of a 100 mm focal length imaging lens and a camera. The surface of the sample was illuminated with the light emanating from an optical fiber bundle to increasing the visibility of the irradiated area. The damage threshold of the multilayer coating was measured to decrease from  $7 \pm 0.5 \text{ J/cm}^2$  for 120 ps pulses to  $0.4 \pm 0.02 \text{ J/cm}^2$  for 120 fs pulses with a value of  $0.87 \pm 0.2 \text{ J/cm}^2$  for 1 ps pulses.

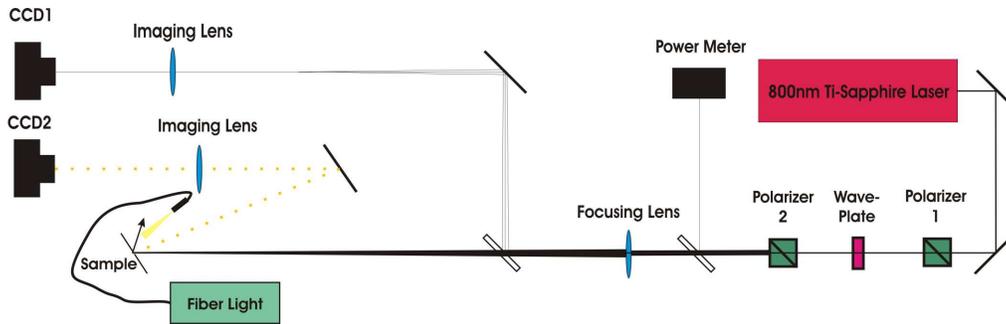


Fig. 7. Schematic diagram of the setup used to determine damage threshold.

Damage threshold measurements were also performed on the finished MLD grating structures using 50 mm diameter ridealong samples. The measured damage threshold using the S-polarized Ti:sapphire beam with an incident angle of 55 degrees varied from  $1.76 \pm 0.1 \text{ J/cm}^2$ , down to  $0.18 \pm 0.02 \text{ J/cm}^2$  for pulsewidths ranging from 120 ps down to 120 fs respectively. Table 2 summarizes the results of the measurements. The damage threshold of the gratings for 1 ps pulses is  $\sim 2.4$  times lower than that of the MLD interference coating. This is due to increased electric field at the edges of the grating ridges [8,11].

Table 2. Damage threshold of MLD stack and MLD gratings at 55 degrees

	120 fs	1 ps	10 ps	120 ps
MLD Stack ( $\text{J/cm}^2$ )	$0.40 \pm 0.02$	$0.87 \pm 0.06$	$2.3 \pm 0.2$	$7.07 \pm 0.5$
MLD Grating ( $\text{J/cm}^2$ )	$0.18 \pm 0.02$	$0.37 \pm 0.02$	$0.74 \pm 0.04$	$1.76 \pm 0.1$

## 6. Pulse compression results

A set of four (229 mm x 114 mm) MLD gratings were used to setup a double pass vacuum compressor for the compression of 5.5 J pulses from a Ti:sapphire laser. The photograph displayed in Fig. 8 shows a partial view of the compressor in which two of the gratings are visible. The compressor was configured to compress 220 ps Ti:sapphire pulses that had been chirped by a grating stretcher implemented using a MLD grating produced in the same run. In this configuration the grating compressor has a bandwidth acceptance of 60 nm for a beam diameter of 96 mm. Although the measured spectral performance data shows the gratings will support the compression of 25 fs pulses, the separation of the gratings was set to generate pulses of 3-6 picosecond durations which are optimum for the excitation of transient collisional soft x-ray lasers in several elements [12-14]. The throughput of the compressor was measured to be greater than 80%. We have used the gratings to compress input pulses of 5.5 J at repetition rates up to 2.5 Hz for several months without observing any grating degradation. Interferometry of the grating surface, subjected to several times this average fluence detected no measurable deformation, showing these MLD gratings are suited for high average power applications. This is in contrast with a previous setup that made use of gold coated replica gratings where we observed wavefront distortion due to thermal deformation at similar fluences. In another application we used smaller gratings made in the same fabrication process to compress pulses to pulsewidths below 70 fs, verifying that the MLD gratings have the bandwidth necessary for high average power femtosecond laser applications.

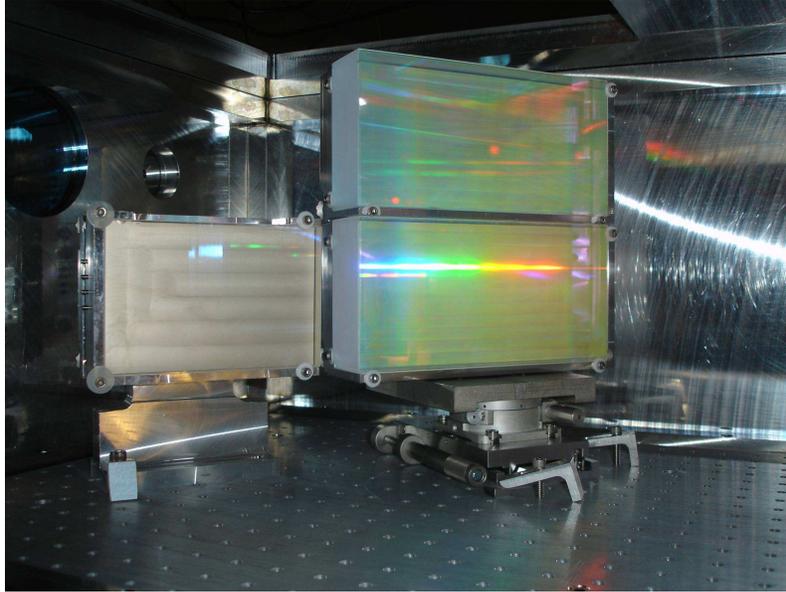


Fig. 8. Photograph of two 229mm x 114 mm dielectric gratings that are part of a vacuum pulse compressor for high energy Ti:sapphire laser pulses.

## 7. Conclusions

We have developed durable broad bandwidth high efficiency large area  $\lambda = 800$  nm multilayer dielectric diffraction gratings for pulse compression of high energy Ti-Sapphire laser pulses at high average power. The MLD gratings have a mean efficiency that is better than 97% at the center wavelength and remains above 96% at wavelengths of 820 nm and 780 nm. The gratings were employed in the implementation of a high energy vacuum compressor with a throughput greater than 80%. The compressor was used to generate picosecond duration Ti:sapphire laser pulses with an energy  $\sim 4.5$  J at a repetition rate of up to 2.5 Hz for several months without signs of degradation.

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